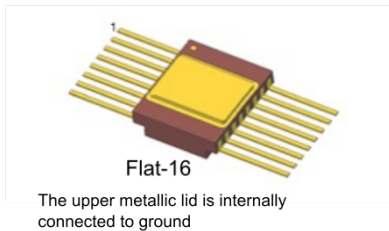


Rad-hard, 8-channel, 50 kbps to 1 Mbps, 12-bit A/D converter



Features

- 50 kbps to 1 Mbps conversion rate
- 8-to-1-channel single input MUX
- 4-to-1-channel differential input MUX
- 2.7 to 3.6 V operating supply
- Independent analog and digital supplies
- Pure CMOS
- Very low consumption: 1.65 mA typ. @ 3.6 V
- SPI, serial digital output
- Power-down function
- 300 krad TID
- 125 MeV.cm²/mg SEL free

Applications

- Analog multiplexing and conversion in space and harsh environments
- Telemetry
- Housekeeping

Description

The **RHFAD128** is specifically designed to sustain ionizing dose and heavy-ions for space applications by using a high-end proven CMOS technology.

This device is a low-power, multiplexed eight-channel 12-bit analog-to-digital converter for conversion from 50 kbps to 1 Mbps. The architecture is based on the successive-approximation register with internal track-and-hold. The **RHFAD128** features 8 analog inputs which can be programmed to be either 8-single ended or 4 differential inputs using the control register bits. The output serial data are straight binary and are compatible with SPI™.

The analog and digital power supplies operate from 2.7 V to 3.6 V, drawing a current consumption of 1.65 mA typ. and 2 mA max. only.

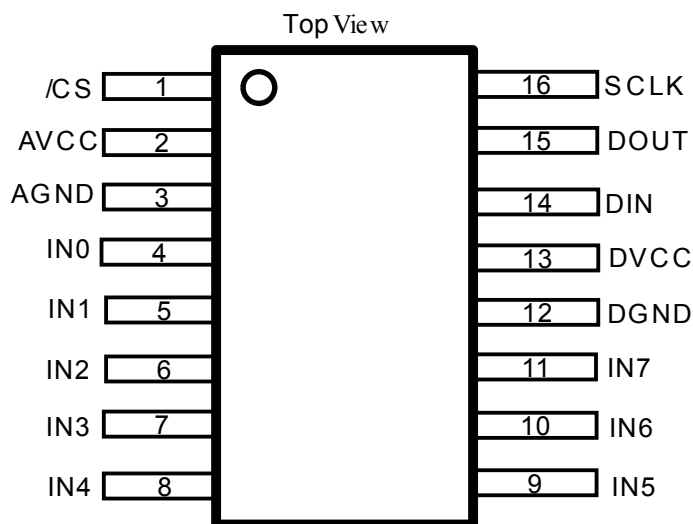
The **RHFAD128** is in hermetic ceramic Flat-16 leads, and works from -55 °C to + 125 °C ambient temperature.

Product status link

[RHFAD128](#)

1 Functional description

Figure 1. Pin description



Note: the upper metallic lid is internally connected to ground.

Figure 2. Block diagram

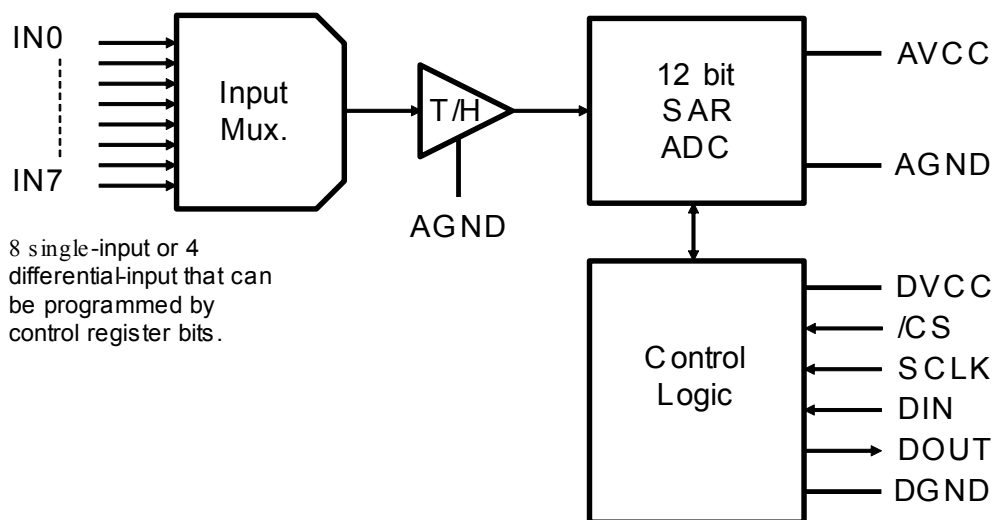


Table 1. Control register bits

| Bit# | 7 (MSB) | 6 | 5 | 4 | 3 | 2 | 1 | 0 |
|-------------------------------|--------------------|---|------|------|------|---------------------|---|---|
| Symbol for single input | Any code except 11 | | ADD2 | ADD1 | ADD0 | Any code except 001 | | |
| Symbol for differential input | 1 | 1 | 0 | ADD1 | ADD0 | 0 | 0 | 1 |

Table 2. Single input channel description

| ADD2 | ADD1 | ADD0 | Input channel |
|------|------|------|---------------|
| 0 | 0 | 0 | IN0 |
| 0 | 0 | 1 | IN1 |
| 0 | 1 | 0 | IN2 |
| 0 | 1 | 1 | IN3 |
| 1 | 0 | 0 | IN4 |
| 1 | 0 | 1 | IN5 |
| 1 | 1 | 0 | IN6 |
| 1 | 1 | 1 | IN7 |

Table 3. Differential input channel description

| ADD1 | ADD0 | Differential channel |
|------|------|----------------------|
| 0 | 0 | IN0-IN1 |
| 0 | 1 | IN2-IN3 |
| 1 | 0 | IN4-IN5 |
| 1 | 1 | IN6-IN7 |

1.1 Maximum ratings and operating conditions

Absolute maximum ratings are those values beyond which damage to the device may occur. Functional operations under these conditions is not implied.

Table 4. Absolute maximum ratings

| Symbol | Parameters | Value | Unit |
|---------------------|---|-----------------------------------|------|
| AVCC ⁽¹⁾ | Maximum analog power supply between AVCC and AGND | -0.3 V to 4.8 V | V |
| DVCC ⁽¹⁾ | Maximum digital power supply between DVCC and DGND | -0.3 V to AVCC+0.3 V (4.8 V max.) | V |
| T _{stg} | Maximum temperature storage | -65 to +150 | °C |
| T _j | Maximum junction temperature | +150 | °C |
| R _{thja} | Junction-to-ambient thermal resistance (Flat-16 package) ⁽²⁾ | 120 | °C/W |
| R _{thjc} | Junction-to-case thermal resistance (Flat-16 package) ⁽²⁾ | 22 | °C/W |
| V _i | Max. voltage on any pin vs. GND | -0.3 V to AVCC+0.3 V (4.8 V max.) | V |
| I _i | Max. input current at any pin | ±10 | mA |
| ESD | HBM on all pins (human body model) | 4 k | V |

1. All voltages, except differential I/O bus voltage, refer to the network ground level.
2. Short-circuits can cause excessive heating. Destructive dissipation can result from short-circuits on the amplifiers.

Table 5. Operating conditions

| Symbol | Parameters | Min. | Max. | Unit |
|----------------|--|-------------|-------------|------|
| AVCC | Analog supply voltage | 2.7 | 3.6 | V |
| DVCC | Digital supply voltage | AVCC - 0.15 | AVCC + 0.15 | V |
| VIN | Analog input voltage in single-ended | 0 | AVCC | V |
| | Analog input voltage in differential configuration, and VICM=AVCC/2 (see Figure 7. True-differential input range) | -AVCC | AVCC | |
| VICM | Common mode in differential configuration | 0 | AVCC | V |
| VIND | Digital input voltage | 0 | AVCC | V |
| SCLK | Clock frequency | 0.1 | 16 | MHz |
| T _a | Ambient temperature range | -55 | +125 | °C |

1.2 Electrical characteristics

AVCC = DVCC = +3.3 V, single-ended input, AGND = DGND = 0 V, f_{SCLK} = 0.8 MHz to 16 MHz, f_{SAMPLE} = 50 kps to 1 Msps, CL = 50 pF, typ. values at +25 °C, min./max. values at -55 °C/125 °C, unless otherwise specified.

Table 6. Electrical characteristics in single-ended input

| Symbol | Parameters | Test conditions | Min. | Typ. | Max. | Unit |
|--|---|---|------|------|------|------|
| Static characteristics | | | | | | |
| | Resolution without missing codes | | | | 12 | Bits |
| INL | Integral non-linearity (end-point method) | | −1.1 | ±0.6 | 1.1 | LSB |
| DNL | Differential non-linearity | | −0.9 | ±0.5 | 0.9 | LSB |
| OE | Offset error | | −2.3 | 0.8 | 2.3 | LSB |
| OEM | Offset error match | | −2 | ±0.1 | 2 | LSB |
| FSE | Full scale error | | −2 | 0.8 | 2 | LSB |
| FSEM | Full scale error match | | −2 | | 2 | LSB |
| Dynamic characteristics | | | | | | |
| FPBW | Full power bandwidth-3 dB | | | 6.8 | | MHz |
| SINAD | Signal-to-noise plus distortion ratio (0 to Fs/2) | FIN = 40.2 kHz, −0.02 dBFS | 68 | 72 | | dB |
| SNR | Signal-to-noise ratio (0 to Fs/2) | | 69 | 71 | | dB |
| THD | Total harmonic distortion | | | −80 | −74 | dB |
| SFDR | Spurious-free dynamic range (0 to Fs/2) | | 75 | 81 | | dB |
| ENOB | Effective number of bits | | 11.1 | 11.4 | | Bits |
| ISO | Channel-to-channel isolation | FIN = 20 kHz, −0.02 dBFS | 80 | 84 | | dB |
| IM2 | 2 nd order intermodulation | f _a = 19.5 kHz, | | −90 | −78 | dB |
| IM3 | 3 rd order intermodulation | f _b = 20.5 kHz VINA=VINB=−6.02 dBFS | | −90 | −72 | dB |
| Analog input characteristics | | | | | | |
| IDCL | DC leakage current | | −1 | | 1 | μA |
| CINA | Input capacitance | Track mode | | 45 | | pF |
| | | Hold mode | | 4.5 | | pF |
| Digital input characteristics | | | | | | |
| VIH | Input high voltage | | 2.1 | | | V |
| VIL | Input low voltage | | | | 0.8 | V |
| IIN | Digital input current | VIN = 0 V or DVCC | −1 | | 1 | μA |
| CIND | Digital input capacitance | | | 3.5 | | pF |
| Digital output characteristics, output coding: straight (natural) binary | | | | | | |
| VOH | Output high voltage | I _{source} =1 mA | 2.8 | | | V |

| Symbol | Parameters | Test conditions | Min. | Typ. | Max. | Unit |
|--|---|---|------|------------------------------|------|---------------|
| VOL | Output low voltage | $I_{\text{sink}}=1 \text{ mA}$ | | | 0.4 | V |
| IOZH, IOZL | Hi-impedance output leakage current | | -1 | | 1 | μA |
| COUT | Hi impedance output capacitance | | | 3.5 | | pF |
| Power supply characteristics, $CL=10 \text{ pF}$ | | | | | | |
| IAVCC + IDVCC | Total supply current, normal mode (CS low) | AVCC = DVCC = +2.7 V to +3.6 V, $f_S=1 \text{ MSPS}$, $F_{\text{IN}}=40 \text{ kHz}$ | | 1.65 | 2 | mA |
| | Total supply current, shutdown mode (CS high) | AVCC = DVCC = +2.7 V to +3.6 V, $f_S=0$ | | 2 | 10 | μA |
| AC characteristics (AVCC = DVCC = +2.7 V to +3.6 V) | | | | | | |
| t_{CONVERT} | Conversion (hold) time | | | 13 | | SCLK cycles |
| DC | SCLK duty cycle | | 40 | | 60 | % |
| t_{ACQ} | Acquisition (track) time cycles | See Figure 5. Serial timing diagram | | 3 | | SCLK cycles |
| | Throughput time Acquisition time + Conversion time | | | 16 | | SCLK cycles |
| t_{AD} | Aperture delay | | | 4 | | ns |
| Timing specifications (AVCC = DVCC = +2.7 V to +3.6 V) ⁽¹⁾ | | | | | | |
| t_{CSH} | CS/ hold time after SCLK rising edge | ⁽²⁾ | 10 | 0 | | ns |
| t_{CSS} | CS/ setup time prior SCLK rising edge | ⁽²⁾ | 10 | 4.5 | | ns |
| t_{EN} | CS/ falling edge to DOUT enabled | | | 5 | 30 | ns |
| t_{DACC} | DOUT access time after SCLK falling edge | | | 17 | 27 | ns |
| t_{DHLD} | DOUT hold time after SCLK falling edge | | 7 | | | ns |
| t_{DS} | DIN setup time prior to SCLK rising edge | | 10 | | | ns |
| t_{DH} | DIN hold time after SCLK rising edge | | 10 | | | ns |
| t_{DIS} | CS/ rising edge to DOUT high-impedance | DOUT falling | | 2.4 | 20 | ns |
| | | DOUT rising | | 0.9 | 20 | ns |
| t_{CH} | Min. SCLK high time | | | $0.4 \times t_{\text{SCLK}}$ | | ns |
| t_{CL} | Min. SCLK low time | | | $0.4 \times t_{\text{SCLK}}$ | | ns |

1. Limits are guaranteed by functional test.

2. Clock may be in any state (high or low) when CS/ goes high. Set-up and hold time restrictions apply to CS/ going low only.

AVCC = DVCC = +3.3 V, differential input (see figure 4 for configuration), AGND = DGND = 0 V, $f_{SCLK} = 16$ MHz, $f_{SAMPLE} = 1$ Msps, CL = 50 pF, typ. values at +25 °C, min./max. values at -55 °C/125 °C, unless otherwise specified.

Table 7. Electrical characteristics in differential input

| Symbol | Parameters | Test conditions | Min. | Typ. | Max. | Unit |
|-------------------------|--|---|------|------|------|------|
| Static characteristics | | | | | | |
| INL | Integral non-linearity (end point method) | VICM=AVCC/2 | -0.9 | ±0.3 | 0.9 | LSB |
| DNL | Differential non-linearity | | -0.8 | ±0.3 | 0.8 | LSB |
| OE | Offset error | | -1.5 | 0.2 | 1.5 | LSB |
| OEM | Offset error match | | -1.5 | ±0.3 | 1.5 | LSB |
| FSE | Full scale error | | -2 | 0.5 | 2 | LSB |
| FSEM | Full scale error match | | -2 | | 2 | LSB |
| Dynamic characteristics | | | | | | |
| SINAD | Signal-to-noise plus distortion ratio (0 to Fs/2) | FIN=40.2 kHz, -0.02 dBFS | 69.3 | 72 | | dB |
| SNR | Signal-to-noise ratio (0 to Fs/2) | | 71 | 73 | | dB |
| THD | Total harmonic distortion | | | -80 | -74 | dB |
| SFDR | Spurious-free dynamic range (0 to Fs/2) | | 75 | 81 | | dB |
| ENOB | Effective number of bits | | 11.2 | 11.6 | | Bits |
| ISO | Channel-to-channel isolation | FIN=20 kHz, -0.02 dBFS | 85 | 95 | | dB |
| IM2 | 2 nd order intermodulation | f _a = 19.5 kHz, f _b =20.5 kHz VINA=VINB=-6.02 dBFS | | -90 | -78 | dB |
| IM3 | 3 rd order intermodulation | f _a = 19.5 kHz, f _b =20.5 kHz VINA=VINB=- 6.02 dBFS | | -90 | -72 | dB |

1.3 Radiations

Total dose (MIL-STD-883 TM 1019):

The products guaranteed in radiation within the RHA QML-V system fully comply with the MIL-STD-883 TM 1019 specification.

The RHFAD128 is RHA QML-V, tested and characterized in full compliance with the MIL-STD-883 specification, between 50 and 300 rad/s only (full CMOS technology).

All provided parameters in [Table 6. Electrical characteristics in single-ended input](#) apply to both pre- and post-irradiation, as follows:

- All tests are performed in accordance with MIL-PRF-38535 and test method 1019 of MIL-STD-883 for total ionizing dose (TID)
- The initial characterization is performed in qualification only on both biased and unbiased parts
- Each wafer lot is tested at high dose rate only, in the worst bias case condition, based on the results obtained during the initial qualification

Heavy-ions:

The behavior of the product when submitted to heavy-ions is not tested in production. Heavy-ion trials are performed on qualification lots only.

Table 8. Radiations

| Type | Characteristics | Value | Unit |
|--------------------|---|-------|------------|
| TID ⁽¹⁾ | High dose rate (50 - 300 rad/s) up to | 300 | krad |
| Heavy-ions | SEL immune up to (with a particle angle of 60 ° at 125 °C, and a fluence of 1e7 cm-2) | 125 | MeV.cm²/mg |
| | SEL immune up to (with a particle angle of 0 ° at 125 °C, and a fluence of 1e7 cm-2) | 62 | |
| | SEU immune up to (at 25 °C, and a fluence of 1e6 cm-2) | 32 | |
| | SEFI immune up to (at 25 °C, and a fluence of 1e6 cm-2) | 62 | |

1. Total ionizing dose (TID) of 300 krad(Si) is equivalent to 3000 Gy(Si), (1 gray = 100 rad).

Note:

- *SEL: single event latch-up*
- *SEU: single event upset*
- *SEFI: single event functional interrupt*

Figure 3. Operational timing diagram in single-ended input

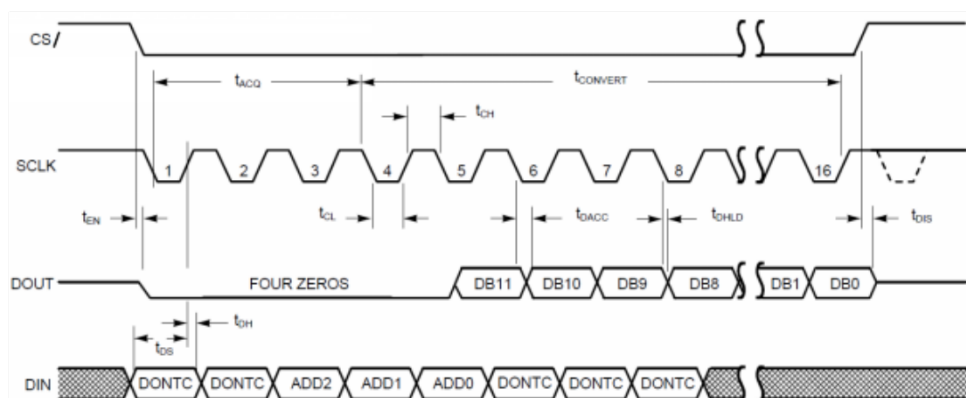
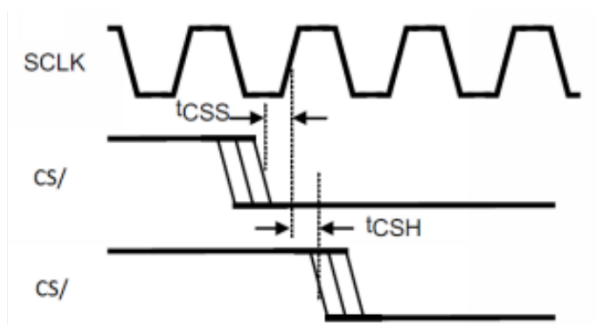
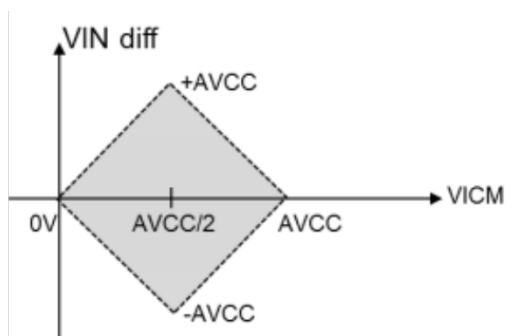


Figure 6. SCLK and CS/ timings



1.5 Differential input

Figure 7. True-differential input range



The maximum differential input swing is limited by the input common mode value (V_{ICM}) and it is limited by the grey area as shown in [Figure 7. True-differential input range](#). The maximum value equals to $\pm AVCC$ for $V_{ICM} = AVCC/2$.

1.6 Definitions

- **Acquisition time** is the time required to acquire the input voltage. During this time, the hold capacitor is charged by the input voltage
- **Aperture delay** is the time between the fourth falling edge of SCLK and the time when the input signal is internally acquired or held for conversion
- **Channel-to-channel isolation** is the residual noise injected on the selected channel by other unselected channels
- **Conversion time** is the time required, after the input voltage is acquired, to convert the input voltage to a digital word
- **Differential non-linearity (DNL)** is the maximum deviation from the ideal step size of 1 LSB
- **Duty cycle** is the ratio, for a periodic digital signal, of the high level duration divided by the total period
- **Effective number of bits (ENOB)** is a method to specify signal-to-noise and distortion or SINAD. ENOB is defined as $(\text{SINAD} - 1.76) / 6.02$ and says that the converter is equivalent to a perfect ADC of this (ENOB) number of bits
- **Full power bandwidth** is a measure of the frequency at which the reconstructed output fundamental drops 3 dB below its low frequency value for a full scale input
- **Full scale error (single-ended input)** is the deviation of the last code transition (111...110) to (111...111) from the ideal (AVCC -1LSB), after adjusting for offset error
- **Positive full scale error (differential input)** is the deviation of the last code transition (111...110) to (111...111) from the ideal (AVCC -1LSB), after adjusting for offset error
- **Negative full scale error (differential input)** is the deviation of the last code transition (111...110) to (111...111) from the ideal (-AVCC +1LSB), after adjusting for offset error
- **Integral non-linearity (INL)** is the deviation of each individual code from a line drawn from negative full scale ($\frac{1}{2}$ LSB below the first code transition) through positive full scale ($\frac{1}{2}$ LSB above the last code transition). The deviation of any given code from this straight line is measured from the center of that code value
- **Intermodulation distortion (IMD)** is the result of the product of two pure sine waves at frequency f_a and f_b applied to the ADC input. To avoid clipping when the sine waves are in phase, the level must be just below -6 dBFS. Assuming that the level of the two tones is equal, IMD2 is the difference in dBc between level (f_a or f_b) and level($f_a \pm f_b$). IMD3 is the difference in dBc between level (f_a or f_b) and level ($2f_a \pm f_b$) or level ($f_a \pm 2f_b$)
- **Missing codes** are those output codes that never appear on the ADC outputs. The RHFAD128 is guaranteed not to have any missing codes
- **Offset error (single-ended input)** is the deviation of the first code transition (000...000) to (000...001) from the ideal (i.e. GND +1 LSB)
- **Signal-to-noise ratio (SNR)** is the ratio, expressed in dB, of the RMS value of the fundamental of input signal to the RMS value of the sum of all other spectral components below one-half the sampling frequency, not including harmonics or DC-component
- **Signal-to-noise plus distortion (S/N+D or SINAD)** is the ratio of the RMS value of the fundamental of input signal to the RMS value of all of the other spectral components below half the sampling frequency, including harmonics but excluding DC-component
- **Spurious free dynamic range (SFDR)** is the difference, expressed in dB, between the desired signal amplitude of fundamental to the amplitude of the peak spurious spectral component, where a spurious spectral component is any signal present in the output spectrum that is not present on the input and may or may not be a harmonic
- **Total harmonic distortion (THD)** is the ratio, expressed in dBc, of the RMS total of the first nine harmonic components on the output to the RMS level of fundamental of the input signal frequency as seen on the output. THD is calculated as $\text{THD} = 20 \log_{10} [\sqrt{(Af_2^2 + \dots + Af_{10}^2) / Af_1^2}]$ where Af_1 is the RMS power of the fundamental on the output and Af_2 to Af_{10} are the RMS power in the first nine harmonic frequencies
- **Throughput time** is the minimum time required between the start of two successive conversions. It is the acquisition time plus the conversion time

1.7 PCB layout precautions

- A ground plane on each layer of the PCB with multiple vias dedicated to interconnection is recommended for high speed circuit applications to provide low parasitic inductance and resistance. The goal is to have a “common ground plane” where AGND and DGND are connected with the lowest DC resistance and lowest AC impedance
- The separation of the analog signal from the digital output is mandatory to prevent noise from coupling onto the input signal
- Power supply bypass capacitors must be placed as close as possible to the IC pins to improve high frequency bypassing and reduce harmonic distortion
- All leads must be as short as possible, especially for the analog input, so to decrease parasitic capacitance and inductance
- To minimize the transition current when the output changes, the capacitive load at the digital outputs must be reduced as much as possible by using the shortest possible routing tracks
- Choose the smallest possible component sizes (SMD)

2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

2.1 Flat-16 package information

The upper metallic lid is electrically connected to AGND and DGND.

Figure 8. Flat-16 package information outline

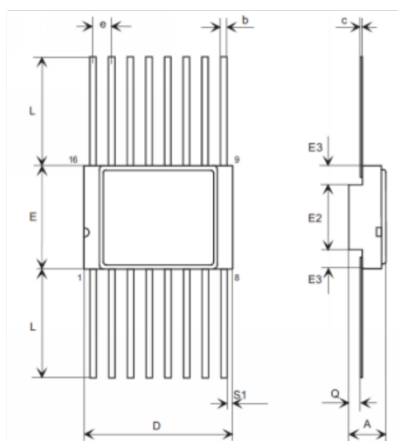


Table 9. Flat-16 package mechanical data

| Ref. | mm | | | Inch | | |
|------|------|------|-------|-------|-------|-------|
| | Min. | Typ. | Max. | Min. | Typ. | Max. |
| A | 2.31 | | 2.72 | 0.091 | | 0.107 |
| b | 0.38 | | 0.48 | 0.015 | | 0.019 |
| c | 0.10 | | 0.18 | 0.004 | | 0.007 |
| D | 9.75 | | 10.13 | 0.384 | | 0.399 |
| E | 6.75 | | 7.06 | 0.266 | | 0.278 |
| E2 | | 4.32 | | | 0.170 | |
| E3 | 0.76 | | | 0.030 | | |
| e | | 1.27 | | | 0.050 | |
| L | 6.35 | | 7.36 | 0.250 | | 0.290 |
| Q | 0.66 | | 1.14 | 0.026 | | 0.045 |
| S1 | 0.13 | | | 0.005 | | |

3 Ordering information

Table 10. Order code

| Order code | SMD ⁽¹⁾ | Quality level | Temp. range | Mass | Package | Marking ⁽²⁾ | Packing |
|--------------|--------------------|-------------------|-------------------|--------|---------|------------------------|------------|
| RH-AD128KX | - | Prototype | -55 °C to +125 °C | 0.65 g | Flat-16 | RH-AD128KX | Strip pack |
| RH-AD128K1 | - | Engineering model | | | | RH-AD128K1 | |
| RHFAD128K01V | 5962F18204 | QML-V Flight | | | | 5962F1820401VXC | |

1. Standard microcircuit drawing.

2. • Specific marking only. Complete marking includes the following:
- ST logo
 - Date code (date the package was sealed) in YYWWA (year, week, and lot index of week)
 - Country of origin (FR = France).

4 Other information

Date code:

The date code is structured as follows:

Engineering model: EM xyywwz

where:

x = 3 (EM only), assembly location Rennes (France)

yy = last two digits of the year

ww = week digits

z = lot index of the week

Product documentation

Each product shipment includes a set of associated documentation within the shipment box. This documentation depends on the quality level of the products, as detailed in the table below.

The certificate of conformance is provided on paper whatever the quality level. For QML parts, complete documentation, including the certificate of conformance, is provided on a CDROM.

Note: Please, contact ST for details on the documentation of other quality levels

Table 11. Product documentation

| Quality level | Item |
|-------------------|---|
| Engineering model | Certificate of conformance including : Customer name Customer purchase order number ST sales order number and item ST part number Quantity delivered Date code Reference to ST datasheet Reference to the TN1181 on engineering models ST Rennes assembly lot ID |

| Quality level | Item |
|---------------|--|
| QML-V Flight | Certificate of conformance including |
| | Customer name |
| | Customer purchase order number |
| | ST sales order number and item |
| | ST part number |
| | Quantity delivered |
| | Date code |
| | Serial numbers |
| | Group C reference |
| | Group D reference |
| | Reference to the applicable SMD |
| | ST Rennes assembly lot ID |
| | Quality control inspection (groups A, B, C, D, E) |
| | Screening electrical data in/out summary |
| | Pre-cap report |
| | PIND (particle impact noise detection) test |
| | SEM (scanning electronic microscope) inspection report |
| | X-ray plates |

Revision history

Table 12. Document revision history

| Date | Revision | Changes |
|-------------|----------|--|
| 12-Mar-2018 | 1 | Initial version. |
| 06-Sep-2018 | 2 | Updated , Section Features and the Section Description in cover page. Updated Section 1 Functional description , Table 4. Absolute maximum ratings , Table 6. Electrical characteristics in single-ended input and Table 7. Electrical characteristics in differential input , Table 8. Radiations and Table 10. Order code . |

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